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Magnetic and Transport Properties of $La_{0.67}Pb_{0.33}(Mn_{1-x}Co_x)O_3$

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Detailed studies of temperature dependences of magnetization, AC susceptibility and electrical resistance were performed on La_{0.67}Pb_{0.33}(Mn_{1-x}Co_x)O₃ ceramics with x = 0.01 and 0.1. Typical features of both compounds are the hysteretic behavior between the zero-field-cooled magnetization regime and the field-cooled magnetization regime, a very weak field dependence of a maximum in zero-field-cooled magnetization and practically no frequency dependence of the peak in AC susceptibility $\chi''(T)$. Anomalies in the electrical resistance connected with the ferromagnetic transition at $T_{\rm C}$, the insulator-metal transitions at $T_{\rm p}$ and the re-entrant metal-isolator transition at T^* are field dependent pointing to magnetic origin of these transitions. Colossal magnetoresistance was observed in both compounds.

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1. Introduction

The mixed-valence perovskite manganese oxides have been studied for almost 60 years. Recent work has been driven by a desire to understand and exploit the large negative magnetoresistance effect [1]. Pb-doped lanthanum manganates were first reported during a study of ionic ferromagnets of the general composition $(\text{La}_{1-x}M_x)\text{MnO}_3$, where M was a divalent cation, either Ca, Sr, Ba Cd or Pb [2]. A mixed valence of $\text{Mn}^{3+}/\text{Mn}^{4+}$ is needed for both metallic behavior and ferromagnetism in these materials [3]. Pb-doped lanthanum manganates with partial substitution of Mn by transition metal cation such as Fe, Co or Ni were investigated [3–5]. Our recent study [6] revealed that $\text{La}_{0.67}\text{Pb}_{0.33}(\text{Mn}_{1-x}\text{Co}_x)\text{O}_{3-\delta}$ ceramics with $x \leq 0.15$ crystallize in rhombohedral crystal structure (space group $R\bar{3}c$). All compounds undergo a paramagnetic–ferromagnetic phase transition between 225 K and 335 K. The Curie temperature $T_{\rm C}$, the effective magnetic moment $\mu_{\rm eff}$, and the saturated magnetization $\mu_{\rm s}$ decrease with increasing Co-doping. The

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ferromagnetic transition is accompanied by an anomaly in the electrical resistance. The high-temperature insulator-metal (I–M) transition at $T_{\rm p}$ decreased with Codoping but the re-entrant temperature T^* , observed at low temperatures, increases with Co-doping. The metal-insulator transitions do not coincide with the relevant Curie temperatures. A large magnetoresistance (MR) peak of about 15% was observed for all compounds at $T_{\rm C}$ ($\mu_0 H = 1$ T). Here we discuss possible spinglass and cluster-glass behavior. We extended magnetoresistance measurements to magnetic field with induction of 9 T.

2. Experimental

The preparation of the ceramic samples followed the malic acid gel method and in details is described in [6]. Details of the crystal structure and characterization of both samples were published in [6]. Magnetization and AC susceptibility measurements were performed in magnetic fields up to 5 T and in the temperature range between 1.8 K and 380 K by a commercial SQUID magnetometer (MPMS -Quantum Design). Electrical resistance measurements were carried out on PPMS equipment (Quantum Design) using the AC-transport method in magnetic fields up to 9 T and in the temperature range between 1.8 K and 360 K.

3. Results and discussions

Figure 1 shows the temperature dependence of the magnetization M for both compounds measured in the zero-field-cooled (ZFC) regime and the field-cooled (FC) regime at different magnetic fields. Both compounds undergo paramagnetic– ferromagnetic phase transition. The ferromagnetic character of the undoped compound still remains after Co-doping [6]. This is mainly due to the double-exchange (DE) mechanism that arises from the ratio of Mn^{3+} to Mn^{4+} . Magnetization in the ZFC regime for x = 0.01 below $T_{\rm C}$ remains at first constant and then at $T_{\rm AF}$ decreases with decreasing temperature. Below this temperature the strength of the DE interaction between Mn^{3+} and Mn^{4+} ions, mediated by Mn–O–Mn bonds, is reduced and the superexchange antiferromagnetic interaction is dominant. We assumed that trivalent Co replaces trivalent Mn sites. Co-doping induces antiferromagnetic coupling due to the reduction of DE interaction, and/or a dilution

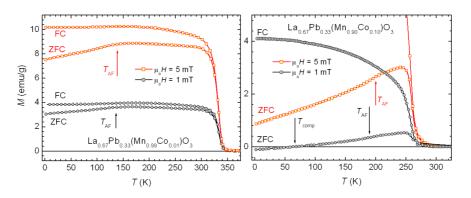


Fig. 1. ZFC and FC magnetization measured in two different magnetic fields.

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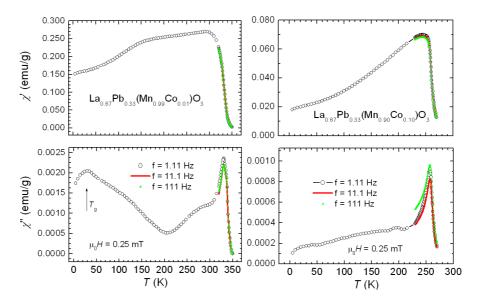


Fig. 2. Temperature variation of AC susceptibility measured for both compounds.

effect by Co^{3+} ions, which are mainly in the low-spin state with S = 0 [6]. As a consequence $T_{\rm C}$ is reduced and $T_{\rm AF}$ rises with doping (see Fig. 1). Similarly as for x = 0.15 [6] compensation temperature $T_{\rm comp}$ was observed for material with x = 0.10 in the ZFC regime. The hysteretic behavior between ZFC and FC regimes in low magnetic fields is a typical feature of this system [6]. Magnetization bifurcates at the temperature of irreversibility $T_{\rm irr}$ which is very close to $T_{\rm C}$. For the compound with x = 0.01 the FC magnetic curves show a nearly constant value of magnetization below $T_{\rm irr}$ (Fig. 1). Such behavior is typical of canonical spin glass systems. On the other hand, FC magnetization continues to increase strongly below T_{irr} for x = 0.10, a typical feature of cluster glass systems. A small cusp below $T_{\rm C}$ which is stronger for x = 0.10 is field independent. The in-phase component $\chi'(T)$ of the AC susceptibility follows M(T) data and $T_{\rm AF}$ is seen in Fig. 2. The Curie temperatures $T_{\rm C}$ determined as a minimum on $d\chi/dT(T)$ correspond very well with the results published for DC susceptibility in [6]. The characteristic feature of out-of-phase component $\chi''(T)$ of AC susceptibility is a sharp peak below $T_{\rm C}$ which is only weakly frequency dependent and the position of the peak does not change with frequency. $\chi''(T)$ for x = 0.01 at first decreases, showing a shoulder, a minimum, and a peak at $T_{\rm g}$, which may indicate the freezing temperature.

The transition at $T_{\rm C}$ is accompanied by an anomaly in the electrical resistance $\rho(T)$ (Fig. 3a,b). Anomalies connected with the insulator-metal transitions at $T_{\rm p}$ and the re-entrant transition at T^* become stronger with Co-doping [6]. Sensitivity of the anomalies at $T_{\rm p}$ and T^* in $\rho(T)$ on magnetic field indicates their magnetic origin. The applied field smears out the anomalies [6]. The difference

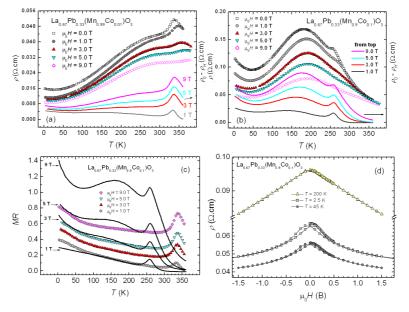


Fig. 3. Variation of electrical resistance with magnetic field: temperature dependence (a) and (b); magnetoresistance (c); hysteresis behavior at different temperatures (d).

 $\rho_0 - \rho_H$ is large not only at $T_{\rm C}$ but at $T_{\rm p}$ and below T^* . The effect becomes stronger with Co-doping [6]. Similar effects are observed for magnetoresistance $MR = \Delta \rho / \rho_H = (\rho_0 - \rho_H) / \rho_H$ (Fig. 3c). The low-field magnetoresistance shows a butterfly curve at low temperature with the resistance greater for the virgin state. The hysteresis loop is reversible with the peak resistance corresponding to the coercive field (Fig. 3d).

Acknowledgments

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